

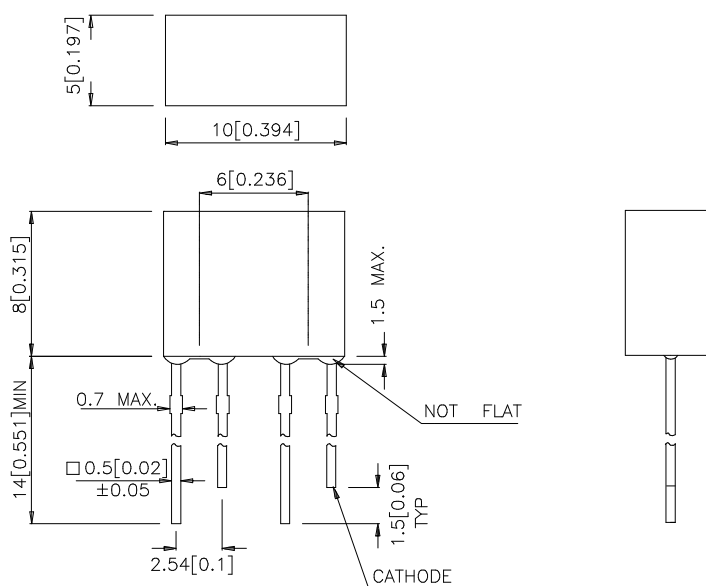
Features

- UNIFORM LIGHT EMITTING AREA.
- EASILY MOUNTED ON P.C. BOARDS OR INDUSTRY STANDARD SOCKETS.
- FLUSH MOUNTABLE.
- EXCELLENT ON/OFF CONTRAST.
- CAN BE USED WITH PANELS AND LEGEND MOUNTS.
- MECHANICALLY RUGGED.
- I.C. COMPATIBLE.
- BOTTOM SURFACE OF EPOXY IS NOT FLAT.

Description

The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	2θ1/2
W835/2SRDT	SUPER BRIGHT RED (GaAlAs)	RED DIFFUSED	18	60	120°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Super Bright Red	660		nm	I _F =20mA
λ _D	Dominate Wavelength	Super Bright Red	640		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	Super Bright Red	20		nm	I _F =20mA
C	Capacitance	Super Bright Red	45		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	Super Bright Red	1.85	2.5	V	I _F =20mA
I _R	Reverse Current	Super Bright Red		10	uA	V _R = 5V

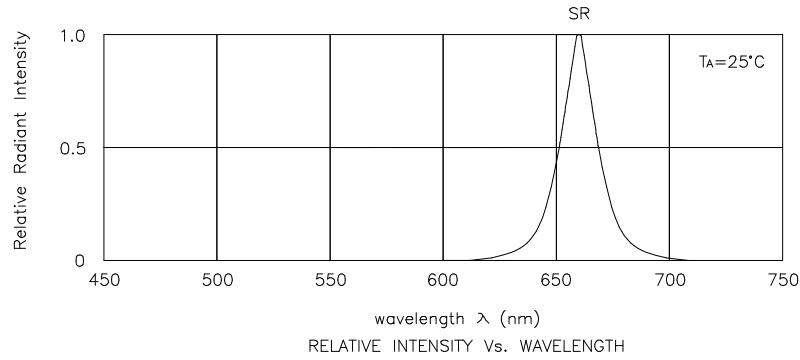
Absolute Maximum Ratings at T_A=25°C

Parameter	Super Bright Red	Units
Power dissipation	100	mW
DC Forward Current	30	mA
Peak Forward Current [1]	155	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.



Super Bright Red

W835/2SRDT

